

TBC- XNP Series High Precision Closed Loop Mode Hall Effect Current Sensor





TBC-XN/XNP series high-precision current sensor is a closed loop device based on the measuring principle of the hall effect, with a galvanic isolation between primary and secondary circuit. It has strong anti-jamming ability, and it provides accurate electronic measurement of DC, AC or pulsed currents.

Electrical data ((Ta=25°C±5°C, RL=2KΩ, CL=10000PF)

Type Parameter	TBC50XNP	TBC60XNP	TBC100XNP	Unit
Rated input (lpn)	50	60	100	А
Measuring range (Ip)	±150	±150	±150	А
Size of input pins	ø6.0 ×1.2	ø6.0 ×1.2	ø6.0 ×1.2	mm
Turns ratio (Np/Ns)	1 : 2000	1 : 2000	1 : 2000	Т
Inside resistance	20±0.1%	18±0.1%	10±0.1%	Ω
Rated output	@ lp=±lpn	±4±0.5%		
Supply voltage	±15±5%			V
Power consumption	15+IpX(Np/Ns)			mA
Zero voltage	≤±30			
Offset drift	≤±0.5			mV/°C
Output drift	≤±0.5			mV/°C
Linearity	@ lp=0-±lpn ≤0.1			%FS
Response time	@ lp=lpn, 50 A/μS ,10%- <1.0			μS
Band - wi dth	@-3dB DC-200			KHz
Galvanic isolation	@ 50Hz,AC,1min 3.0			KV

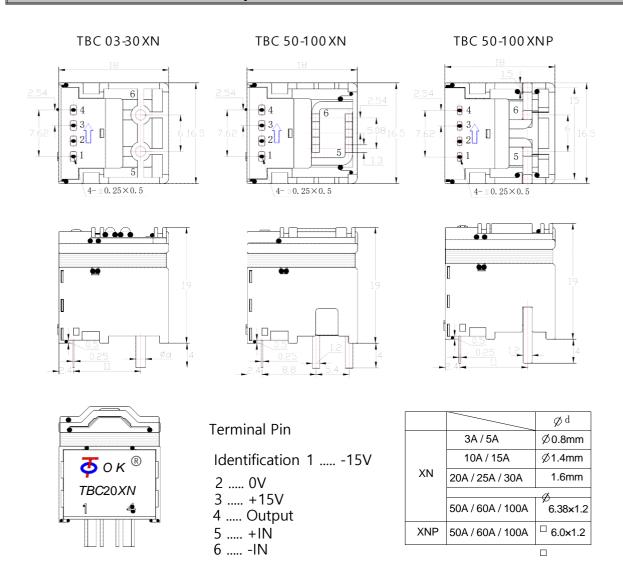


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Applications

- * Switched Mode Power Supplies (SMPS)
- * AC variable speed drives
- * Uninterruptible Power Supplies (UPS)
- * Electrical appliances
- * Battery supplied applications
- * DC motor drives

Mechanical dimension (for reference only)



Remarks:

- 1. All dimensions are in mm.
- 2. Secondary pin size and tolerance: width:0.5±0.1mm;thickness:0.25±0.05mm



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3. General tolerance ±1mm

Directions for use

- 1 . When the current will be measured goes through the primary pin of a sensor, the voltage will be measured at the output end. (Note: The false wiring may result in the damage of the sensor).
- 2 . Custom design in the different rated input current and the output voltage are available.

Standards

UL94-V0.

EN60947-1:2004

IEC60950-1:2001

EN50178:1998

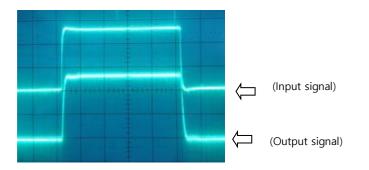
SJ 20790-2000

General data

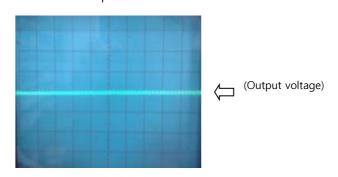
	Value	Unit	Symbol
Operating temperature	-40 to +85	°C	TA
Storage temperature	-40 to +125	°C	TS
Mass(approx)	12	q	М

Characteristics chart

Pulse current signal response characteristic



Effects of impulse noise



Input current-Output Voltage characteristic

